

Micropower Precision, Dual/Quad CMOS Rail-to-Rail Input/Output Amplifiers

FEATURES

- Maximum Offset Voltage of 25 μ V (25°C)
- Maximum Offset Drift of 0.7 μ V/°C
- Maximum Input Bias:
1pA (25°C)
50pA ($\leq$ 85°C)
- Micropower: 54 μ A per Amp
- 95dB CMRR (Min)
- 100dB PSRR (Min)
- Input Noise Voltage Density: 16nV/ $\sqrt{\text{Hz}}$
- Rail-to-Rail Inputs and Outputs
- 2.7V to 5.5V Operation Voltage
- LTC6078 Available in 8-Lead MSOP and 10-Lead DFN Packages; LTC6079 Available in 16-Lead SSOP and DFN Packages

APPLICATIONS

- Photodiode Amplifier
- High Impedance Sensor Amplifier
- Microvolt Accuracy Threshold Detection
- Instrumentation Amplifiers
- Battery Powered Applications

DESCRIPTION

The LTC®6078/LTC6079 are dual/quad, low offset, low noise operational amplifiers with low power consumption and rail-to-rail input/output swing.

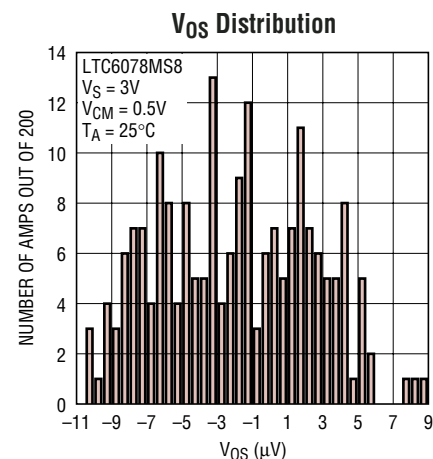
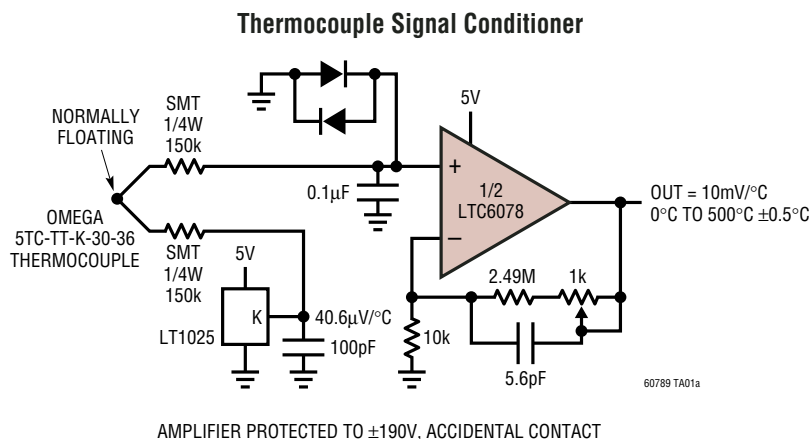
Input offset voltage is trimmed to less than 25 μ V and the CMOS inputs draw less than 50pA of bias current. The low offset drift, excellent CMRR, and high voltage gain make it a good choice for precision signal conditioning.

Each amplifier draws only 54 μ A current on a 3V supply. The micropower, rail-to-rail operation of the LTC6078/LTC6079 is well suited for portable instruments and single supply applications.

The LTC6078/LTC6079 are specified on power supply voltages of 3V and 5V from –40 to 125°C. The dual amplifier LTC6078 is available in 8-lead MSOP and 10-lead DFN packages. The quad amplifier LTC6079 is available in 16-lead SSOP and DFN packages.

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TYPICAL APPLICATION



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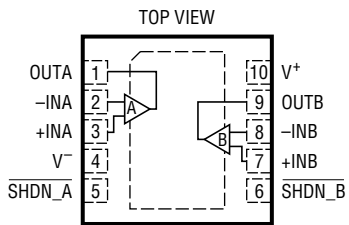
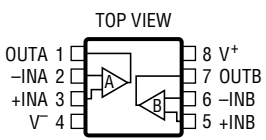
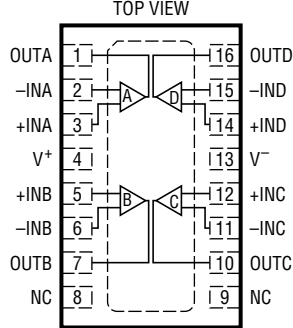
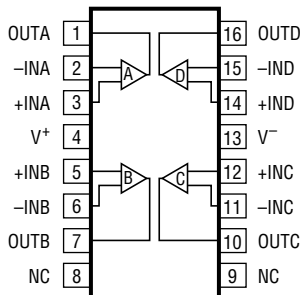
ABSOLUTE MAXIMUM RATINGS

(Note 1)

Total Supply Voltage (V^+ to V^-)	6V
Input Voltage.....	V^- to V^+
Output Short Circuit Duration (Note 2)	Indefinite
Operating Temperature Range (Note 3)	
LTC6078C, LTC6079C	-40°C to 85°C
LTC6078I, LTC6079I	-40°C to 85°C
LTC6078H, LTC6079H.....	-40°C to 125°C
(Not Available in DFN Package)	

Specified Temperature Range (Note 4)	
LTC6078C, LTC6079C	0°C to 70°C
LTC6078I, LTC6079I	-40°C to 85°C
LTC6078H, LTC6079H.....	-40°C to 125°C
Junction Temperature	
DFN Packages.....	125°C
All Other Packages.....	150°C
Storage Temperature Range	
DFN Packages.....	-65°C to 125°C
All Other Packages.....	-65°C to 150°C
Lead Temperature (Soldering, 10 Sec).....	300°C

PACKAGE/ORDER INFORMATION

TOP VIEW  DD PACKAGE 10-LEAD (3mm × 3mm) PLASTIC DFN $T_{JMAX} = 125^{\circ}\text{C}$, $\theta_{JA} = 43^{\circ}\text{C/W}$ UNDERSIDE METAL CONNECTED TO V^-	TOP VIEW  MS8 PACKAGE 8-LEAD PLASTIC MSOP $T_{JMAX} = 150^{\circ}\text{C}$, $\theta_{JA} = 200^{\circ}\text{C/W}$	ORDER PART NUMBER	DD PART MARKING*
		LTC6078CDD LTC6078IDD	LBBB LBBB
		ORDER PART NUMBER	MS8 PART MARKING*
		LTC6078ACMS8 LTC6078CMS8 LTC6078AIMS8 LTC6078IMS8 LTC6078AHMS8 LTC6078HMS8	LTAJZ LTAJZ LTAJZ LTAJZ LTAJZ LTAJZ
TOP VIEW  DHC PACKAGE 16-LEAD (5mm × 3mm) PLASTIC DFN $T_{JMAX} = 125^{\circ}\text{C}$, $\theta_{JA} = 43^{\circ}\text{C/W}$ UNDERSIDE METAL CONNECTED TO V^-	TOP VIEW  GN PACKAGE 16-LEAD PLASTIC SSOP $T_{JMAX} = 150^{\circ}\text{C}$, $\theta_{JA} = 110^{\circ}\text{C/W}$	ORDER PART NUMBER	DHC PART MARKING*
		LTC6079CDHC LTC6079IDHC	6079 6079
		ORDER PART NUMBER	GN PART MARKING
		LTC6079CGN LTC6079IGN LTC6079HGN	6079 6079I 6079H

Order Options Tape and Reel: Add #TR
Lead Free: Add #PBF Lead Free Tape and Reel: Add #TRPBF
Lead Free Part Marking: <http://www.linear.com/leadfree/>

Consult LTC Marketing for parts specified with wider operating temperature ranges.

*The temperature grades and parametric grades are identified by a label on the shipping container.

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. Test conditions are $V^+ = 3\text{V}$, $V^- = 0\text{V}$, $V_{\text{CM}} = 0.5\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	C, I SUFFIXES			H SUFFIX			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Offset Voltage (Note 5)	LTC6078MS8, LTC6078AMS8, LTC6079GN							
		$V_{\text{CM}} = 0.5\text{V}, 2.5\text{V}$		± 7	± 25		± 7	± 25	μV
		LTC6078DD, LTC6079DHC		± 7	± 30				μV
		LTC6078AMS8	●	± 20	± 70		± 25	± 95	μV
		LTC6078MS8	●	± 25	± 97		± 30	± 135	μV
		LTC6079GN	●	± 30	± 115		± 35	± 165	μV
		LTC6078DD	●	± 30	± 120				μV
		LTC6079DHC	●	± 35	± 150				μV
$\Delta V_{\text{OS}}/\Delta T$	Input Offset Voltage Drift (Note 5)	LTC6078AMS8	●	± 0.2	± 0.7		± 0.2	± 0.7	$\mu\text{V}/^\circ\text{C}$
		LTC6078MS8	●		± 1.1			± 1.1	$\mu\text{V}/^\circ\text{C}$
		LTC6078DD, LTC6079GN	●	± 0.3	± 1.4		± 0.3	± 1.4	$\mu\text{V}/^\circ\text{C}$
		LTC6079DHC	●	± 0.3	± 1.8				$\mu\text{V}/^\circ\text{C}$
I_{B}	Input Bias Current (Note 6)	$V_{\text{CM}} = V^+/2$		0.2	1		0.2	1	pA
		$V_{\text{CM}} = V^+/2$	●	10	50		150	350	pA
I_{OS}	Input Offset Current (Note 6)	$V_{\text{CM}} = V^+/2$		0.1			0.1		pA
		$V_{\text{CM}} = V^+/2$	●	0.5	25		10	100	pA
e_{n}	Input Noise Voltage	0.1Hz to 10Hz		1			1		$\mu\text{V}_{\text{P-P}}$
	Input Noise Voltage Density	$f = 1\text{kHz}$		18			18		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 10\text{kHz}$		16			16		$\text{nV}/\sqrt{\text{Hz}}$
i_{n}	Input Noise Current Density (Note 8)			0.56			0.56		$\text{fA}/\sqrt{\text{Hz}}$
	Input Common Mode Range		●	V^-	V^+	V^-	V^+		V
C_{DIFF}	Differential Input Capacitance			10			10		pF
C_{CM}	Common Mode Input Capacitance			18			18		pF
CMRR	Common Mode Rejection Ratio	All Packages		95	110		95	110	dB
		LTC6078AMS8	●	87	105		87	103	dB
		LTC6078AMS8	●	91	103		91	103	dB
		LTC6078MS8	●	85	102		85	100	dB
		LTC6078MS8	●	89	102		89	102	dB
		LTC6079GN	●	84	102		84	100	dB
		LTC6079GN	●	88	102		88	102	dB
		LTC6078DD, LTC6079DHC	●	83	100				dB
		LTC6078DD, LTC6079DHC	●	87	102				dB
PSRR	Power Supply Rejection Ratio	$V_{\text{S}} = 2.7\text{V to } 5.5\text{V}$		100	120		100	120	dB
			●	97			97		dB
V_{OUT}	Output Voltage, High (Referred to V^+)	No Load			1			1	mV
		$I_{\text{SOURCE}} = 0.2\text{mA}$	●	35	15		40	15	mV
		$I_{\text{SOURCE}} = 2\text{mA}$	●	350	150		400	150	mV
	Output Voltage, Low (Referred to V^-)	No Load			1			1	mV
		$I_{\text{SINK}} = 0.2\text{mA}$	●		10			10	mV
		$I_{\text{SINK}} = 2\text{mA}$	●		100			100	mV
A_{VOL}	Large-Signal Voltage Gain	$R_{\text{LOAD}} = 10\text{k}, 0.5\text{V} \leq V_{\text{OUT}} \leq 2.5\text{V}$	●	115	130		110	125	dB
I_{SC}	Output Short-Circuit Current	Source	●	5	10		4	10	mA
		Sink	●	7	14		6	14	mA
SR	Slew Rate	$A_{\text{V}} = 1$			0.05			0.05	V/ μs
GBW	Gain-Bandwidth Product ($f_{\text{TEST}} = 10\text{kHz}$)	$R_{\text{L}} = 100\text{k}$		420	750		420	750	kHz
			●	360			320		kHz
Φ_0	Phase Margin	$R_{\text{L}} = 10\text{k}, C_{\text{L}} = 200\text{pF}$			66			66	Deg
t_{S}	Settling Time 0.1%	$A_{\text{V}} = 1, 1\text{V Step}$			24			24	μs

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LTC6078/LTC6079

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. Test conditions are $V^+ = 3\text{V}$, $V^- = 0\text{V}$, $V_{CM} = 0.5\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		C, I SUFFIXES			H SUFFIX			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
I_S	Supply Current (per Amplifier)	No Load	●		54	72 78		54	72 80	μA μA
	Shutdown Current (per Amplifier)	Shutdown, $V_{SHDN} \leq 0.8\text{V}$, LTC6078DD	●		0.3	1				μA
V_S	Supply Voltage Range	Guaranteed by the PSRR Test	●	2.7		5.5	2.7		5.5	V
	Channel Separation	$f_s = 10\text{kHz}$, $R_L = 10\text{k}$			-110			-110		dB
	Shutdown Logic	$\overline{\text{SHDN}}$ High, LTC6078DD $\overline{\text{SHDN}}$ Low, LTC6078DD	● ●	2		0.8	2		0.8	V V
t_{ON}	Turn on Time	$V_{SHDN} = 0.8\text{V}$ to 2V , LTC6078DD			50			50		μs
t_{OFF}	Turn off Time	$V_{SHDN} = 2\text{V}$ to 0.8V , LTC6078DD			2			2		μs
	Leakage of $\overline{\text{SHDN}}$ Pin	$V_{SHDN} = 0\text{V}$, LTC6078DD			0.6					μA

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. Test conditions are $V^+ = 5\text{V}$, $V^- = 0\text{V}$, $V_{CM} = 0.5\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		C, I SUFFIXES			H SUFFIX			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Offset Voltage	LTC6078MS8, LTC6078AMS8, LTC6079GN $V_{CM} = 0.5\text{V}$ LTC6078DD, LTC6079DHC $V_{CM} = 0.5\text{V}$ LTC6078AMS8 $V_{CM} = 0.5\text{V}$ LTC6078MS8 $V_{CM} = 0.5\text{V}$ LTC6079GN $V_{CM} = 0.5\text{V}$ LTC6078DD $V_{CM} = 0.5\text{V}$ LTC6079DHC $V_{CM} = 0.5\text{V}$	● ● ● ● ● ● ● ●		± 10 ± 10 ± 20 ± 25 ± 30 ± 30 ± 30 ± 35	± 30 ± 35 ± 75 ± 102 ± 120 ± 125 ± 155		± 10 ± 10 ± 25 ± 30 ± 35	± 30 ± 100 ± 140 ± 170	μV μV μV μV μV μV μV μV
$\Delta V_{OS}/\Delta T$	Input Offset Voltage Drift (Note 7)	LTC6078AMS8 LTC6078MS8 LTC6078DD, LTC6079GN LTC6079DHC	● ● ● ●		± 0.2 ± 0.3 ± 0.3	± 0.7 ± 1.1 ± 1.4 ± 1.8		± 0.2 ± 0.3	± 0.7 ± 1.1 ± 1.4	$\mu\text{V}/^\circ\text{C}$ $\mu\text{V}/^\circ\text{C}$ $\mu\text{V}/^\circ\text{C}$ $\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current	$V_{CM} = V^+/2$ $V_{CM} = V^+/2$	●		0.2 10	1 50		0.2 150	1 350	pA pA
I_{OS}	Input Offset Current	$V_{CM} = V^+/2$ $V_{CM} = V^+/2$	●		0.1 0.5	25		0.1 10	100	pA pA
e_n	Input Noise Voltage	0.1Hz to 10Hz			1			1		μV_{P-P}
	Input Noise Voltage Density	$f = 1\text{kHz}$ $f = 10\text{kHz}$			18 16			18 16		$\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$
i_n	Input Noise Current Density (Note 8)				0.56			0.56		$\text{fA}/\sqrt{\text{Hz}}$
	Input Common Mode Range		●	V^-		V^+	V^-		V^+	V
C_{DIFF}	Differential Input Capacitance				10			10		pF
C_{CM}	Common Mode Input Capacitance				18			18		pF

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. Test conditions are $V^+ = 5\text{V}$, $V^- = 0\text{V}$, $V_{\text{CM}} = 0.5\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	C, I SUFFIXES			H SUFFIX			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
CMRR	Common Mode Rejection Ratio	All Packages		91	105	91	105		dB
		LTC6078AMS8 $V_{\text{CM}} = 0\text{V to } 5\text{V}$	●	90	105	90	105		dB
		LTC6078AMS8 $V_{\text{CM}} = 0\text{V to } 3.7\text{V}$	●	94	105	94	105		dB
		LTC6078MS8 $V_{\text{CM}} = 0\text{V to } 5\text{V}$	●	88	100	88	100		dB
		LTC6078MS8 $V_{\text{CM}} = 0\text{V to } 3.7\text{V}$	●	90	105	90	105		dB
		LTC6079GN $V_{\text{CM}} = 0\text{V to } 5\text{V}$	●	86	100	86	100		dB
		LTC6079GN $V_{\text{CM}} = 0\text{V to } 3.7\text{V}$	●	90	105	90	105		dB
		LTC6078DD, LTC6079DHC $V_{\text{CM}} = 0\text{V to } 5\text{V}$	●	86	100				dB
		LTC6078DD, LTC6079DHC $V_{\text{CM}} = 0\text{V to } 3.7\text{V}$	●	90	105				dB
PSRR	Power Supply Rejection Ratio	$V_S = 2.7\text{V to } 5.5\text{V}$		100	120		120		dB
			●	97		97			dB
V_{OUT}	Output Voltage, High (Referred to V^+)	No Load			2		2		mV
		$I_{\text{SOURCE}} = 0.5\text{mA}$	●	50	20	55	20		mV
		$I_{\text{SOURCE}} = 5\text{mA}$	●	500	200	550	200		mV
	Output Voltage, Low (Referred to V^-)	No Load			1		1		mV
		$I_{\text{SINK}} = 0.5\text{mA}$	●		15		15	45	mV
		$I_{\text{SINK}} = 5\text{mA}$	●		150		150	450	mV
A_{VOL}	Large-Signal Voltage Gain	$R_{\text{LOAD}} = 10\text{k}$, $0.5\text{V} \leq V_{\text{OUT}} \leq 4.5\text{V}$	●	115	130	110	125		dB
I_{SC}	Output Short-Circuit Current	Source	●	14	25	12	25		mA
		Sink	●	14	25	12	25		mA
SR	Slew Rate	$A_V = 1$			0.05		0.05		V/ μs
GBW	Gain-Bandwidth Product ($f_{\text{TEST}} = 10\text{kHz}$)	$R_L = 100\text{k}$		420	750	420	750		kHz
			●	360		320			kHz
Φ_0	Phase Margin	$R_L = 10\text{k}$, $C_L = 200\text{pF}$			66		66		Deg
t_S	Settling Time 0.1%	$A_V = 1$, 1V Step			24		24		μs
I_S	Supply Current (per Amplifier)	No Load	●		55	74	55	74	μA
						82		84	μA
	Shutdown Current (per Amplifier)	Shutdown, $V_{\text{SHDN}} \leq 1.2\text{V}$, LTC6078DD	●		1.5	5	1.5	5	μA
V_S	Supply Voltage Range	Guaranteed by the PSRR Test	●	2.7	5.5	2.7	5.5		V
	Channel Separation	$f_S = 10\text{kHz}$, $R_L = 10\text{k}$			-110		-110		dB
	Shutdown Logic	SHDN High , LTC6078DD SHDN Low , LTC6078DD	● ●	3.5	1.2	3.5	1.2		V V
t_{ON}	Turn on Time	$V_{\text{SHDN}} = 1.2\text{V to } 3.5\text{V}$, LTC6078DD			50		50		μs
t_{OFF}	Turn off Time	$V_{\text{SHDN}} = 1.2\text{V to } 3.5\text{V}$, LTC6078DD			2		2		μs
	Leakage of SHDN Pin	$V_{\text{SHDN}} = 0\text{V}$, LTC6078DD			0.6				μA

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: A heat sink may be required to keep the junction temperature below the absolute maximum. This depends on the power supply voltage and how many amplifiers are shorted.

Note 3: The LTC6078C/LTC6079C and LTC6078I/LTC6079I are guaranteed functional over the operating temperature range of -40°C to 85°C . The LTC6078H/LTC6079H are guaranteed functional over the operating temperature range of -40°C to 125°C .

Note 4: The LTC6078C/LTC6079C are guaranteed to meet specified

performance from 0°C to 70°C . The LTC6078C/LTC6079C are designed, characterized and expected to meet specified performance from -40°C to 85°C but are not tested or QA sampled at these temperatures. The LTC6078I/LTC6079I are guaranteed to meet specified performance from -40°C to 85°C . The LTC6078H/LTC6079H are guaranteed to meet specified performance from -40°C to 125°C .

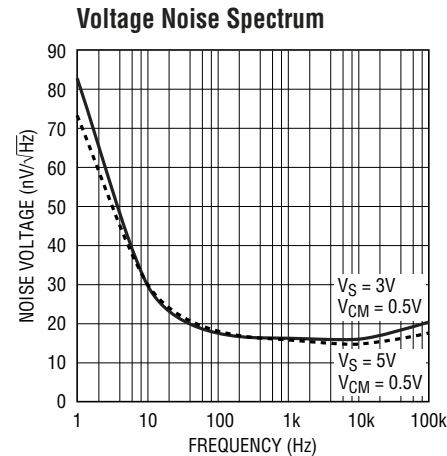
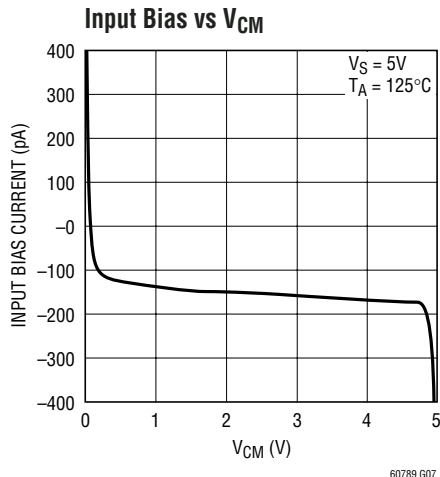
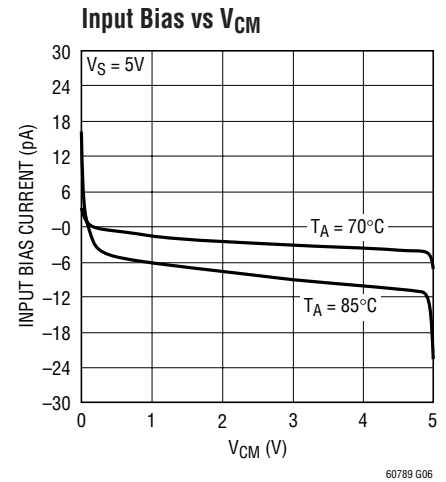
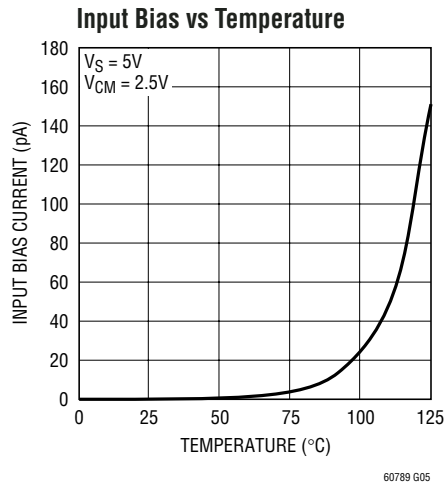
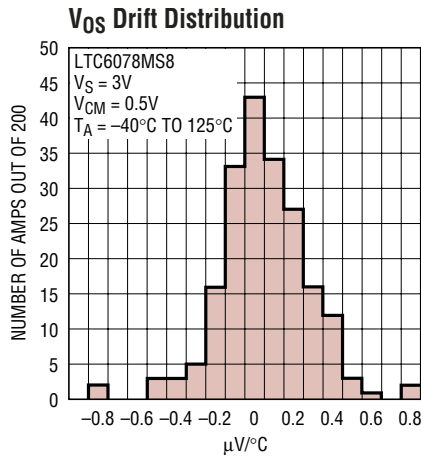
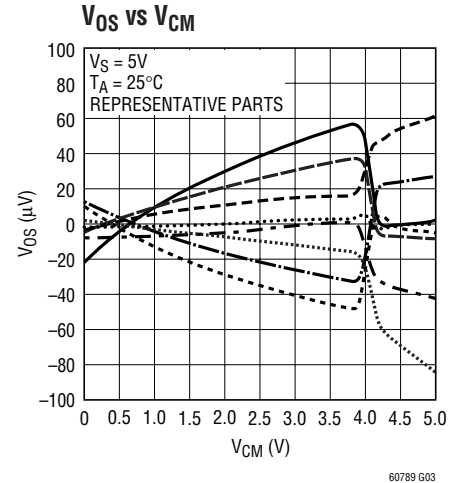
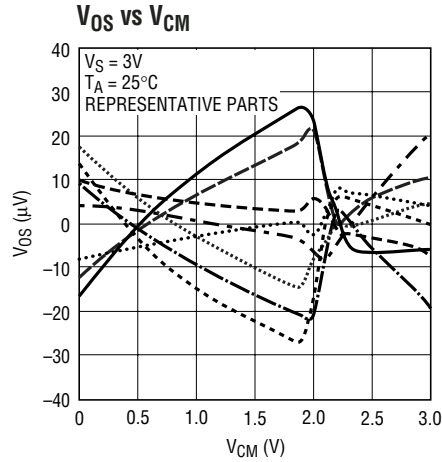
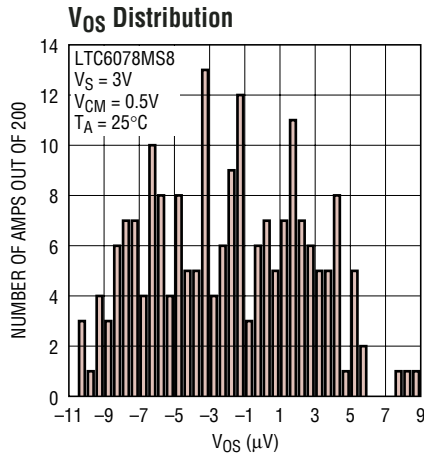
Note 5: V_{OS} and V_{OS} drift are 100% tested at 25°C and 125°C .

Note 6: I_B and I_{OS} are guaranteed by the $V_S = 5\text{V}$ test.

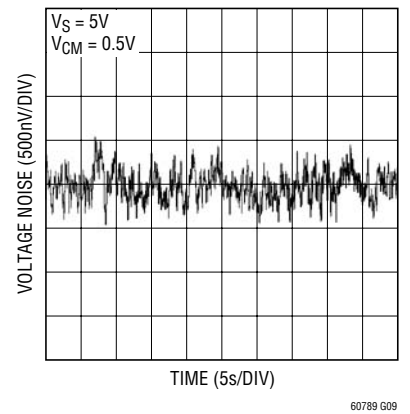
Note 7: V_{OS} drift is guaranteed by the $V_S = 3\text{V}$ test.

Note 8: Current noise is calculated from $i_n = \sqrt{2qI_B}$, where $q = 1.6 \cdot 10^{-19}$ coulomb.

TYPICAL PERFORMANCE CHARACTERISTICS



0.1Hz to 10Hz Output Voltage Noise



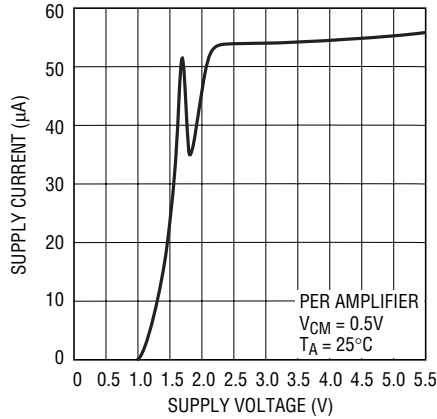
TYPICAL PERFORMANCE CHARACTERISTICS

Output Voltage Swing vs Load Current



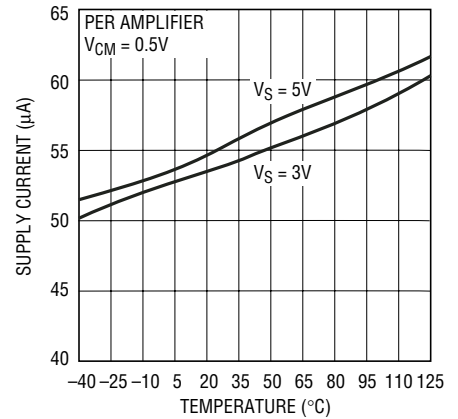
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Supply Current vs Supply Voltage



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Supply Current vs Temperature



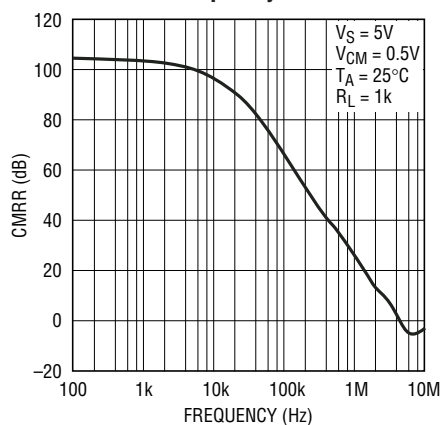
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Open Loop Gain vs Frequency



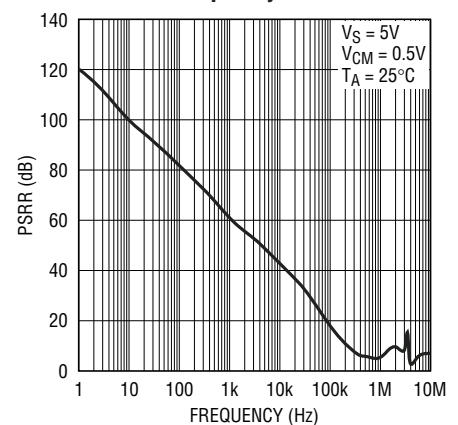
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CMRR vs Frequency



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PSRR vs Frequency



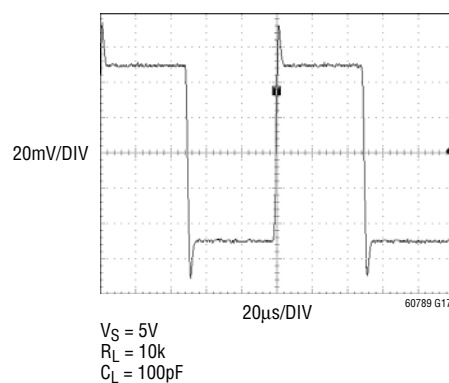
60789 G15

Output Impedance vs Frequency



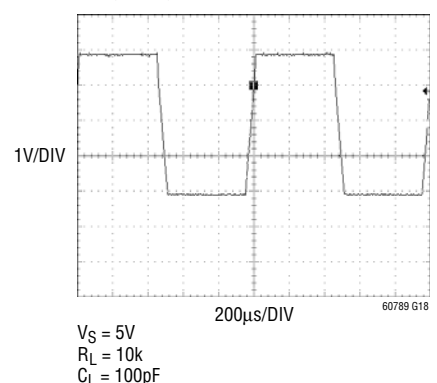
60789 G16

Small Signal Transient



60789 G17

Large Signal Transient



60789 G18

TYPICAL PERFORMANCE CHARACTERISTICS

Disabled Output Impedance vs Frequency



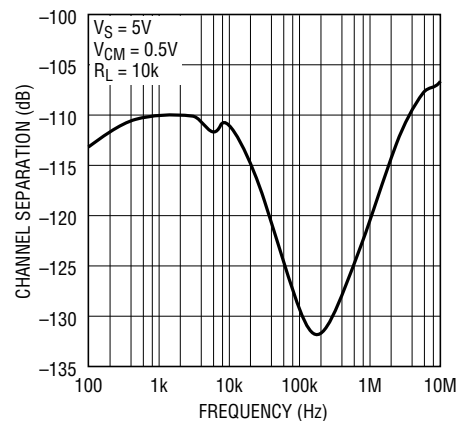
60789 G19

Overshoot vs C_L



60789 G20

Channel Separation vs Frequency



60789 G21

PIN FUNCTIONS

OUT: Amplifier Output

-IN: Inverting Input

+IN: Noninverting Input

V+: Positive Supply

V-: Negative Supply

SHDN_A: Shutdown Pin of Amplifier A, active low and only valid for LTC6078DD. An internal current source pulls the pin to V^+ when floating.

SHDN_B: Shutdown Pin of Amplifier B, active low and only valid for LTC6078DD. An internal current source pulls the pin to V^+ when floating.

NC: Not internally connected.

Exposed Pad: Connected to V^- .

APPLICATIONS INFORMATION

Preserving Input Precision

Preserving input accuracy of the LTC6078/LTC6079 requires that the application circuit and PC board layout do not introduce errors comparable or greater than the $10\mu\text{V}$ typical offset of the amplifiers. Temperature differentials across the input connections can generate thermocouple voltages of 10's of microvolts so the connections to the input leads should be short, close together and away from heat dissipating components. Air current across the board can also generate temperature differentials.

The extremely low input bias currents (0.2pA typical) allow high accuracy to be maintained with high impedance sources and feedback resistors. Leakage currents on the PC board can be higher than the input bias current. For example, $10\text{G}\Omega$ of leakage between a 5V supply lead and an input lead will generate 500pA ! Surround the input leads with a guard ring driven to the same potential as the input common mode to avoid excessive leakage in high impedance applications.

Input Clamps

Large differential voltages across the inputs over very long time periods can impact the precisely trimmed input offset voltage of the LTC6078/LTC6079. As an example, a 2V differential voltage between the inputs over a period of 100 hours can shift the input offset voltage by tens of microvolts. If the amplifier is to be subjected to large differential input voltages, adding back-to-back diodes between the two inputs will minimize this shift and retain the DC precision. If necessary, current-limiting series resistors can be added in front of the diodes, as shown in Figure 1. These diodes are not necessary for normal closed loop applications.

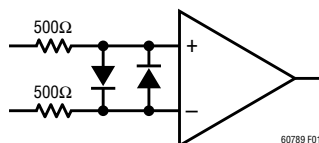


Figure 1. Op Amp with Input Voltage Clamp

Capacitive Load

LTC6078/LTC6079 can drive capacitive load up to 200pF in unity gain. The capacitive load driving capability increases as the amplifier is used in higher gain configurations. A small series resistance between the output and the load further increases the amount of capacitance the amplifier can drive.

SHDN Pins

Pins 5 and 6 are used for power shutdown on the LTC6078 in the DD package. If they are floating, internal current sources pull Pins 5 and 6 to $V+$ and the amplifiers operate normally. In shutdown, the amplifier output is high impedance, and each amplifier draws less than $2\mu\text{A}$ current.

When the chip is turned on, the supply current per amplifier is about $35\mu\text{A}$ larger than its normal values for $50\mu\text{s}$.

Rail-to-Rail Input

The input stage of LTC6078/LTC6079 combines both PMOS and NMOS differential pairs, extending its input common mode voltage range to both positive and negative supply voltages. At high input common mode range, the NMOS pair is on. At low common mode range, the PMOS pair is on. The transition happens when the common voltage is between 1.3V and 0.9V below the positive supply.

Thermal Hysteresis

Figure 2 shows the input offset hysteresis of LTC6078MS8 for 3 thermal cycles from -45°C to 90°C . The typical offset shift after the 3 cycles is only $1\mu\text{V}$.

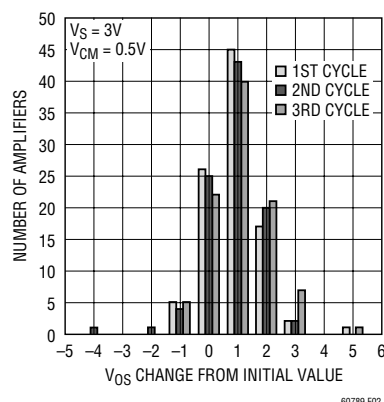


Figure 2. V_{OS} Thermal Hysteresis of LTC6078MS8

APPLICATIONS INFORMATION

PC Board Layout

Mechanical stress on a PC board and soldering-induced stress can cause the V_{OS} and V_{OS} drift to shift. The DD and DHC packages are more sensitive to stress. A simple way to reduce the stress-related shifts is to mount the IC near the short edge of the PC board, or in a corner. The board edge acts as a stress boundary, or a region where the flexure of the board is minimum. The package should always be mounted so that the leads absorb the stress and not the package. The package is generally aligned with the leads parallel to the long side of the PC board.

The most effective technique to relieve the PC board stress is to cut slots in the board around the op amp. These slots can be cut on three sides of the IC and the leads can exit on

the fourth side. Figure 3 shows the layout of a LTC6078DD with slots at three sides.

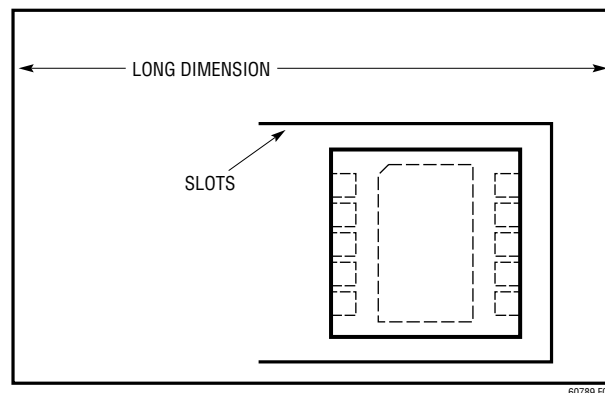
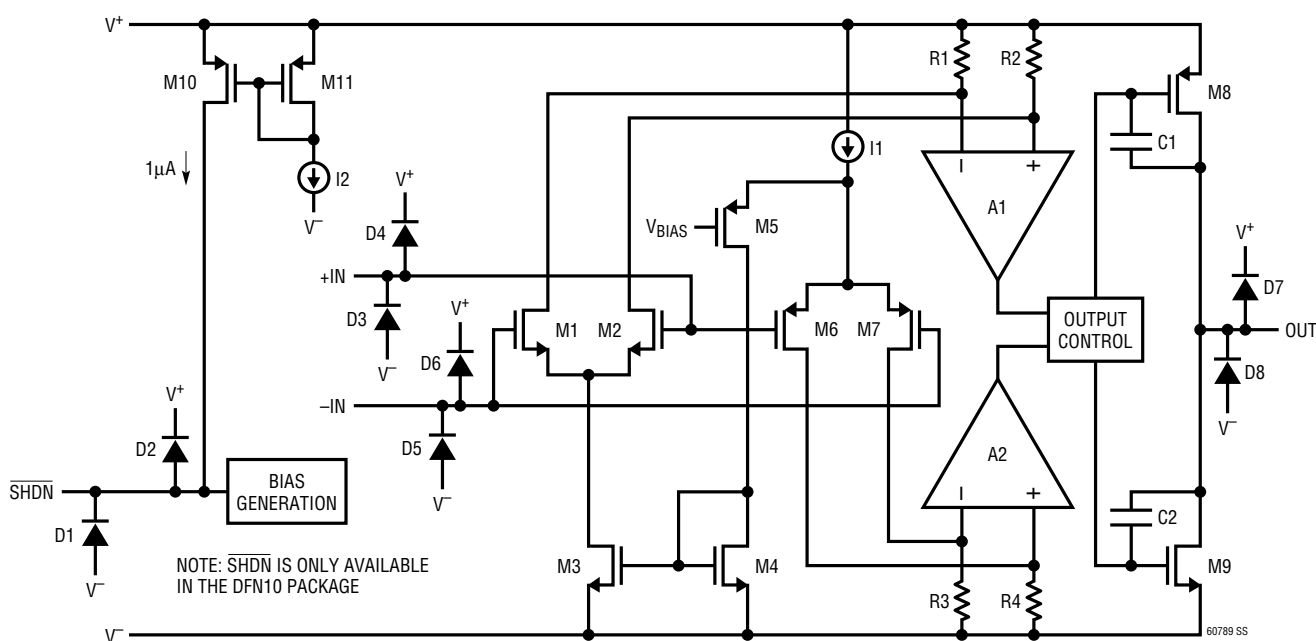


Figure 3. Vertical Orientation of LTC6078DD with Slots

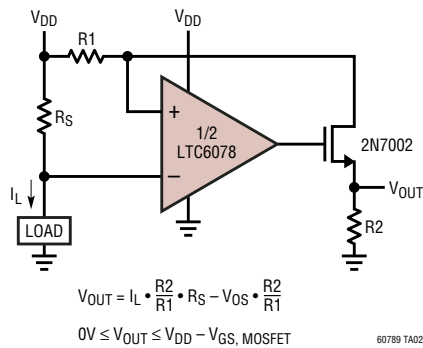
SIMPLIFIED SCHEMATIC



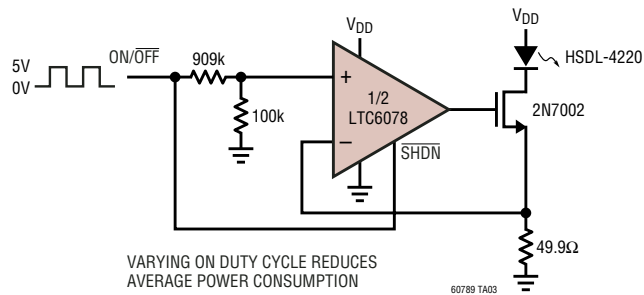
Simplified Schematic of the Amplifier

TYPICAL APPLICATIONS

2.7V High Side Current Sense



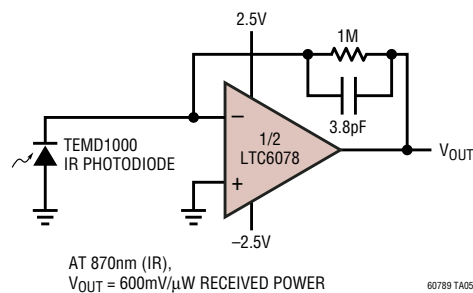
Low Average Power IR LED Driver



Accelerometer Signal Conditioner



Photodiode Amplifier



The circuit diagram shows a precision current-to-voltage converter. An input current source I_{IN} is connected to the non-inverting input of op-amp A. The output of op-amp A is connected to the base of transistor Q1. The emitter of Q1 is connected to ground. The collector of Q1 is connected to the non-inverting input of op-amp D. The output of op-amp D is connected to the base of transistor Q2. The emitter of Q2 is connected to ground. The collector of Q2 is connected to a precision resistor PT146, which is connected to ground. The output voltage V_{OUT} is taken across the resistor. The circuit also includes a feedback network with a 100k resistor and a 1000pF capacitor. The op-amps are configured as buffers. The input current I_{IN} is specified as $10nA \leq I_{IN} \leq 10mA$. The output voltage is given by $V_{OUT} \approx 150mV \cdot \log(I_{IN}) + 1.23V$, where I_{IN} is in amperes. The precision resistor PT146 has a value of 1k and a temperature coefficient of +3500ppm/°C. The op-amp is the LT6650, and the transistors are DMMT3906W.

10nA $\leq$ I_{IN} $\leq$ 10mA
Q1, Q2: DIODES INC. DMMT3906W
A TO D: LTC6079
 $V_{OUT} \approx 150mV \cdot \log(I_{IN}) + 1.23V$, I_{IN} IN AMPS

The schematic diagram illustrates a precision humidity sensor interface circuit. It is divided into three main functional blocks: Power Supply, Sensor Interface, and Signal Processing.

Power Supply: A 5.2V TO 20V input is connected to a 1μF capacitor. The output of the capacitor is connected to the IN pin of the LTC1761-5. The OUT pin of the LTC1761-5 is connected to a 0.01μF capacitor, which is then connected to a 5V output. The SHDN pin of the LTC1761-5 is connected to ground, and the BYP pin is connected to the 5V output.

Sensor Interface: The LTC6906 is configured with VDD connected to the 5V output, OUT connected to the 5V output, GRD connected to ground, and GND connected to ground. The SET pin is connected to a 1MΩ resistor to ground, and the DIV pin is connected to VDD. The output of the LTC6906 is connected to the BAT54S diode. The diode is connected to the IN pin of the LTC1761-5. The OUT pin of the LTC1761-5 is connected to a 0.01μF capacitor, which is then connected to a 5V output.

Signal Processing: The output of the BAT54S diode is connected to the non-inverting input of op-amp A. Op-amp A is configured with a 49.9kΩ resistor from VDD to the non-inverting input, a 49.9kΩ resistor from the non-inverting input to ground, and a 75pF capacitor from the non-inverting input to ground. The output of op-amp A is connected to the non-inverting input of op-amp B. Op-amp B is configured with a 100kΩ resistor from VDD to the non-inverting input, a 100kΩ resistor from the non-inverting input to ground, and a 1000pF capacitor from the non-inverting input to ground. The output of op-amp B is connected to the non-inverting input of op-amp C. Op-amp C is configured with a 34.8kΩ resistor from VDD to the non-inverting input, a 1kΩ resistor from the non-inverting input to ground, and a 100kΩ capacitor from the non-inverting input to ground. The output of op-amp C is connected to the GAIN TRIM potentiometer. The GAIN TRIM potentiometer is connected to the 5V output. The output of the GAIN TRIM potentiometer is connected to the VOUT pin, which is labeled 0V TO 5V 0% TO 100% RH.

Component Values:

- Capacitors: 1μF, 0.01μF, 75pF, 1000pF, 100kΩ, 0.1μF, 1MΩ, 100kΩ, 47.5kΩ, 100kΩ.
- Resistors: 49.9kΩ, 100kΩ, 34.8kΩ, 1kΩ, 10kΩ, 47.5kΩ, 100kΩ.
- Diode: BAT54S.
- Op-amps: LTC6906, LTC1761-5, A, B, C.

Legend:

- A TO C: LTC6079
- H: GE PARAMETRICS G-CAP 2 HUMIDITY SENSOR
- M1: VN2222L

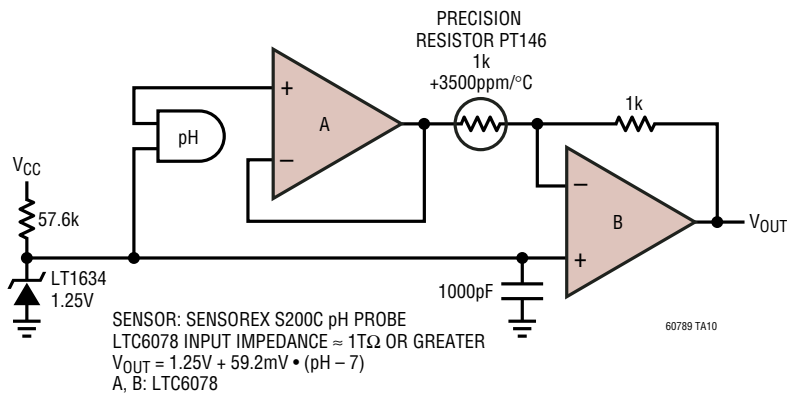
Part Number: 60789 TA08

TYPICAL APPLICATIONS

LDO Load Balancing

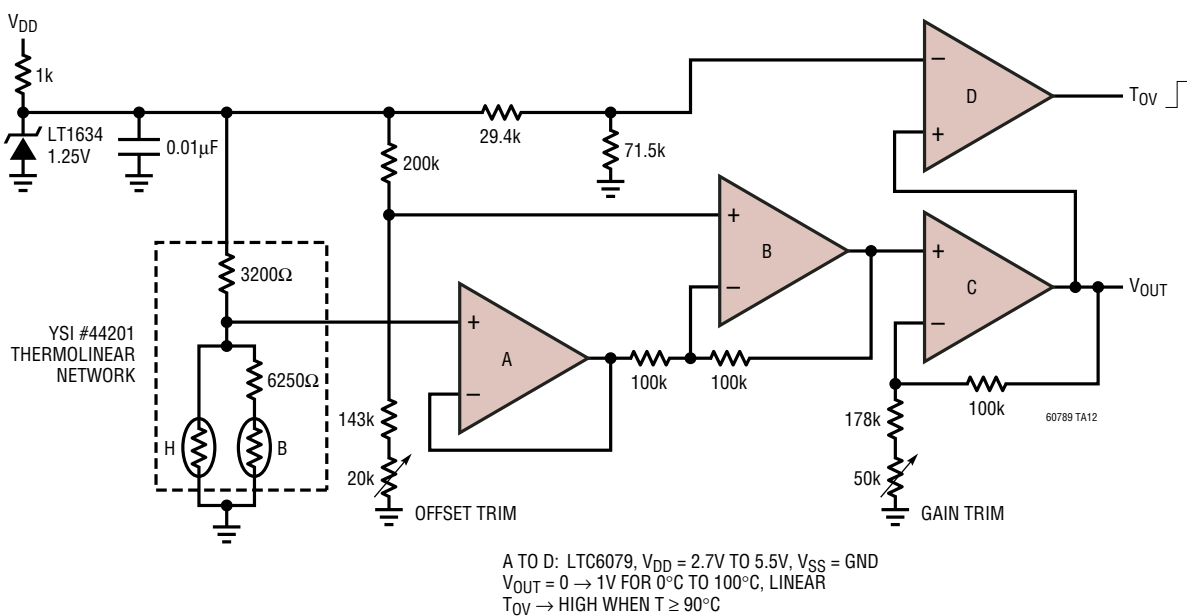


pH Probe Amplifier

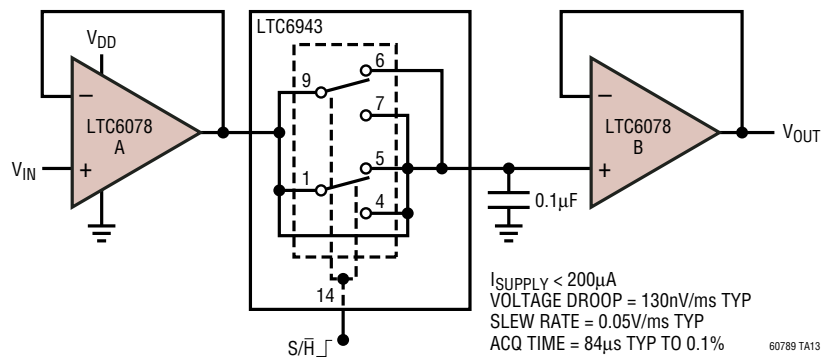


TYPICAL APPLICATIONS

Thermistor Amplifier with Overtemperature Alarm

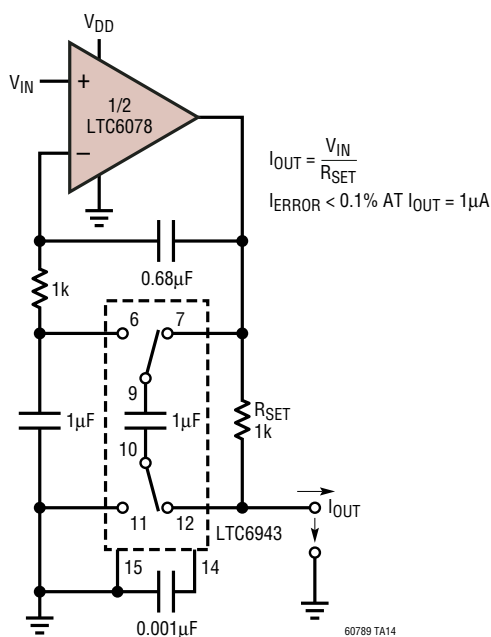


Precision Sample-and-Hold



TYPICAL APPLICATIONS

Precision Voltage-Controlled Current Source



60Hz Notch

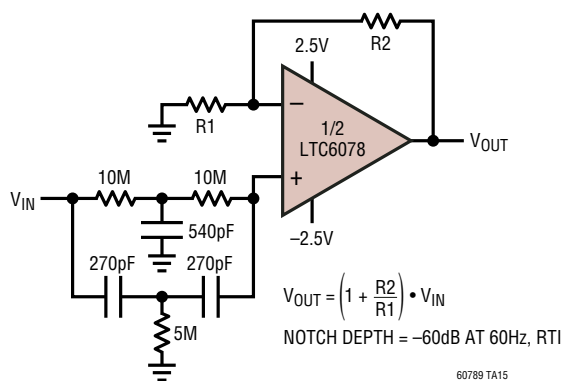


Diagram illustrating the top view of the package with dimensions:

- Overall width: 3.50 ± 0.05
- Distance from top edge to the center of the package: 2.15 ± 0.05
- Distance from the center of the package to the top edge of the package outline: 1.65 ± 0.05 (2 SIDES)
- Distance from the center of the package to the bottom edge of the package outline: 0.675 ± 0.05
- Distance from the center of the package to the left edge of the package outline: 0.25 ± 0.05
- Distance from the center of the package to the right edge of the package outline: 0.50 BSC
- Overall length: 2.38 ± 0.05 (2 SIDES)
- Label: PACKAGE OUTLINE

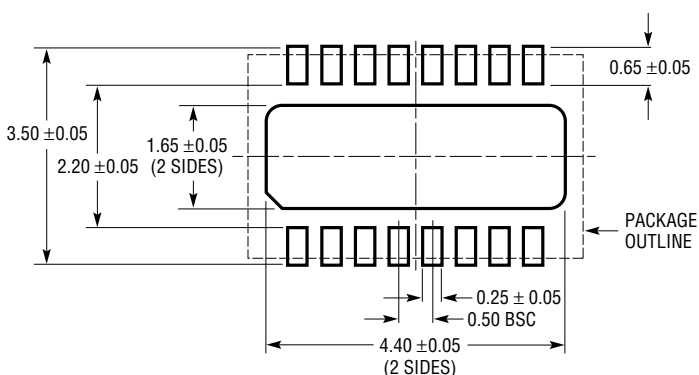
The image contains two mechanical drawings of the 0805 package:

- Top View:** A square package with a side length of 3.00 ± 0.10 (4 SIDES). A circular "PIN 1 TOP MARK (SEE NOTE 6)" is located in the bottom-left corner. A dashed line indicates the center of the package.
- Bottom View—EXPOSED PAD:** Shows the underside of the package with dimensions:
 - Overall width: 2.38 ± 0.10 (2 SIDES)
 - Distance from left edge to center of first pad: 0.25 ± 0.05
 - Pad pitch: 0.50 BSC
 - Distance from right edge to center of last pad: 0.25 ± 0.05
 - Pad diameter: $R = 0.115$ TYP
 - Distance from top edge to center of first pad: 1.65 ± 0.10 (2 SIDES)
 - Distance from bottom edge to center of last pad: $0.00 - 0.05$
 - Distance from left edge to center of last pad: 0.75 ± 0.05
 - Distance from right edge to center of first pad: 0.200 REF

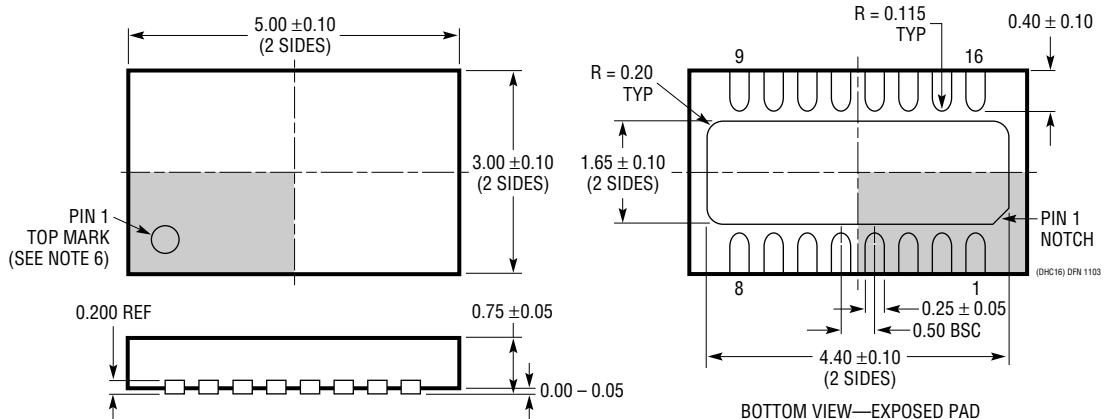
1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE MO-229 VARIATION OF (WEED-2).
CHECK THE LTC WEBSITE DATA SHEET FOR CURRENT STATUS OF VARIATION ASSIGNMENT
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE
MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE
TOP AND BOTTOM OF PACKAGE

PACKAGE DESCRIPTION

DHC Package
16-Lead Plastic DFN (5mm × 3mm)
 (Reference LTC DWG # 05-08-1706)



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS



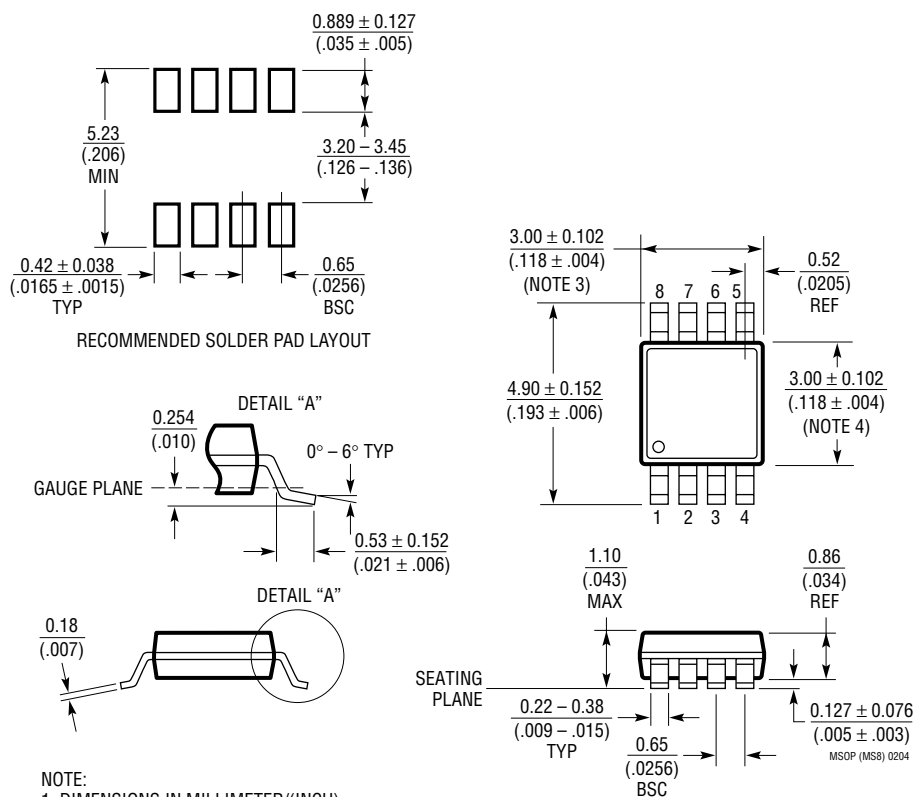
NOTE:

1. DRAWING PROPOSED TO BE MADE VARIATION OF VERSION (WJED-1) IN JEDEC PACKAGE OUTLINE MO-229
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

PACKAGE DESCRIPTION

MS8 Package
8-Lead Plastic MSOP

(Reference LTC DWG # 05-08-1660)

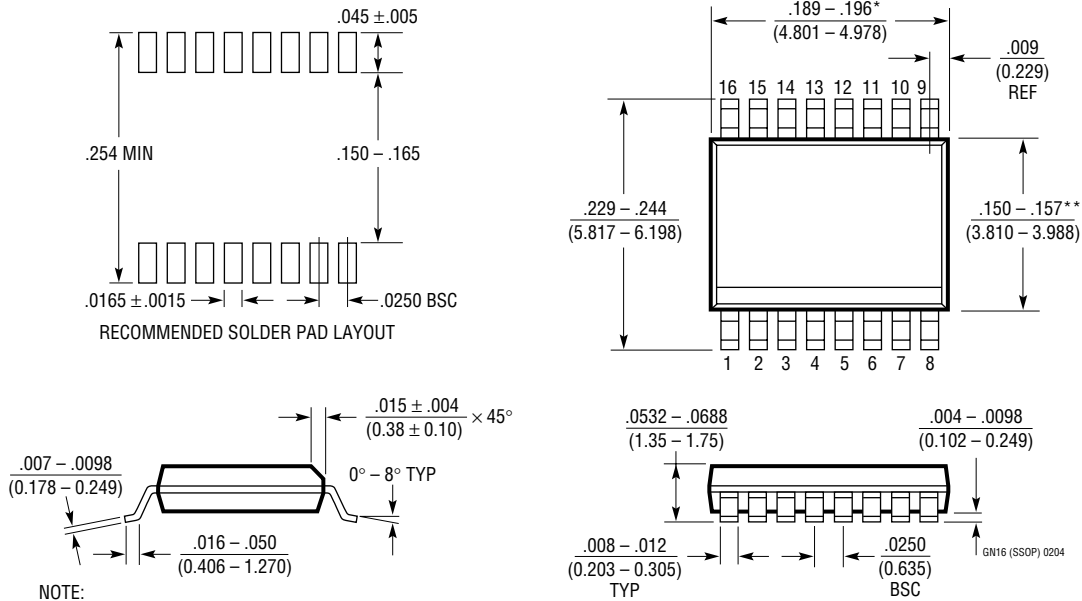


NOTE:

1. DIMENSIONS IN MILLIMETER/(INCH)
2. DRAWING NOT TO SCALE
3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX

PACKAGE DESCRIPTION

GN Package 16-Lead Plastic SSOP (Narrow .150 Inch) (Reference LTC DWG # 05-08-1641)



NOTE:

1. CONTROLLING DIMENSION: INCHES

2. DIMENSIONS ARE IN $\frac{\text{INCHES}}{\text{MILLIMETERS}}$

3. DRAWING NOT TO SCALE

DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006^ (0.152mm) PER SIDE

**DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010^* (0.254mm) PER SIDE

The circuit diagram shows a precision current source. On the left, a voltage divider is connected between V_{CC} and V_{FF} using two $2.49k\Omega$ resistors. The midpoint of this divider is labeled V_{DD} . A diode, labeled LT1634BCS8-5, is connected with its cathode to V_{DD} and its anode to V_{SS} . The V_{SS} terminal is also connected to ground through a 10Ω resistor. The main circuit consists of an LTC6078 op-amp configured as a voltage follower. Its non-inverting input (+) is connected to V_{DD} through a $1M\Omega$ resistor. Its inverting input (-) is connected to the output of the op-amp through a 100Ω resistor. A $0.1\mu F$ capacitor is connected between the inverting input and the output. The output of the LTC6078 is connected to the non-inverting input (+) of an LT1226 op-amp. The LT1226 is configured as a voltage follower, with its inverting input (-) connected to its output. The output of the LT1226 is labeled V_{OUT} . The LT1226's V_{CC} pin is connected to V_{CC} and its V_{EE} pin is connected to V_{SS} . A $10k\Omega$ resistor is connected between the output of the LT1226 and V_{SS} .

CIRCUIT BW $\approx 1.25MHz$
 $e_n = 2.6nV/\sqrt{Hz}$ (RTI) AT 1kHz
 CIRCUIT $V_{OS} = 25\mu V$ (MAX) RTI

60789 TA06

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC2051/LTC2052	Dual/Quad Zero-Drift Op Amps	3μV V _{OS} , 30nV/°C V _{OS} Drift
LT6011/LT6012	Dual/Quad Precision Op Amps	60μV V _{OS} , I _B = 300pA, I _S = 135μA

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